

RJH60M5DPQ-E0

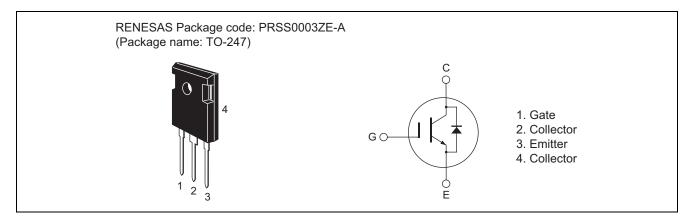
600V - 37A - IGBT Application: Inverter

R07DS1087EJ0200 Rev.2.00 Jun 18, 2013

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.8~V$ typ. (at $I_C=37~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=60 \text{ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=37$ A, $Rg=5$ Ω, $Ta=25^{\circ}$C, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	75	Α
	Tc = 100°C	Ic	37	Α
Collector peak current		I _C (peak) Note1	110	Α
Collector to emitter diode forward current		I _{DF}	30	Α
Collector to emitter diode forward peak current		I _{DF} (peak) Note1	110	Α
Collector dissipation		P _C Note2	200	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.63	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

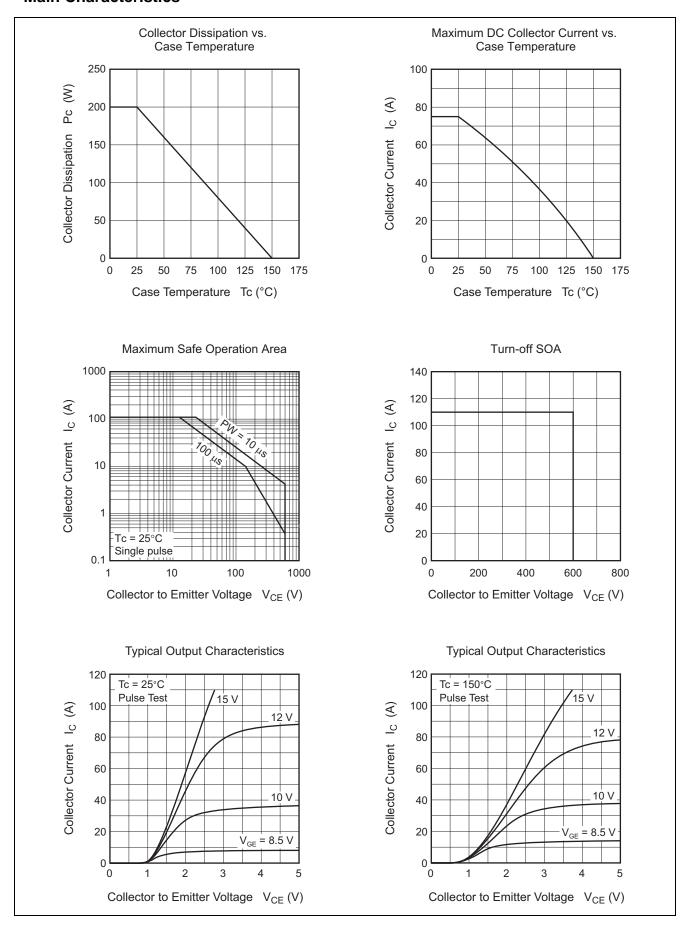
 $(Ta = 25^{\circ}C)$

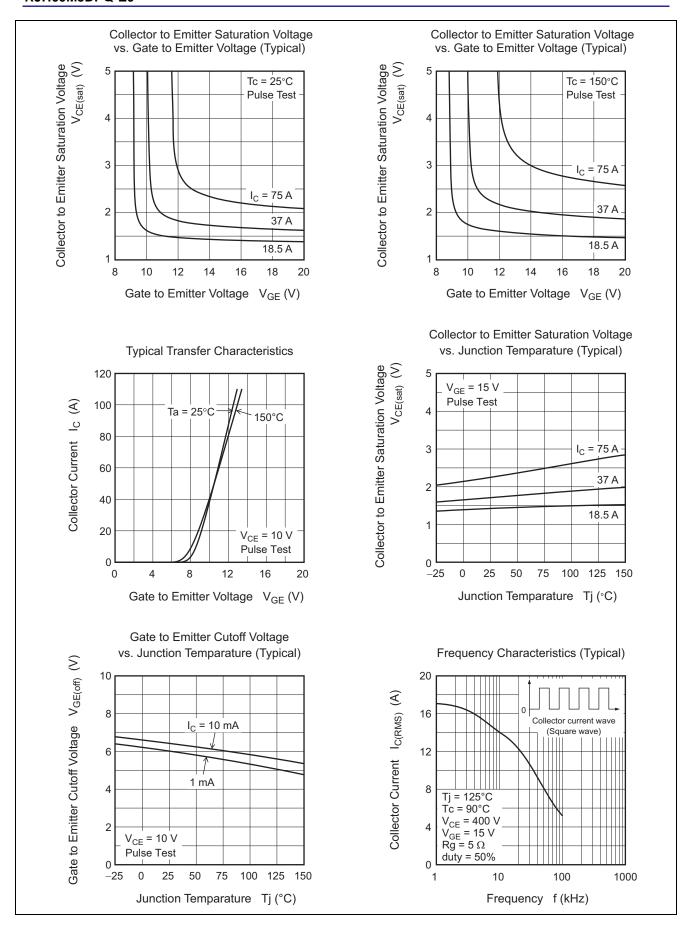
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_C = 37 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	_	2.4	_	V	I _C =75 A, V _{GE} = 15 V ^{Note3}
Input capacitance	Cies	_	1900	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	120	_	pF	V _{GE} = 0 f = 1 MHz
Reverse transfer capacitance	Cres	_	70	_	pF	
Total gate charge	Qg	_	114	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 37 A
Gate to emitter charge	Qge	_	20	_	nC	
Gate to collector charge	Qgc	_	65	_	nC	
Turn-on delay time	t _{d(on)}	_	52	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 37 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Rise time	t _r	_	64	_	ns	
Turn-off delay time	t _{d(off)}	_	147	_	ns	
Fall time	t _f	_	60	_	ns	
Turn-on energy	Eon	_	1.06	_	mJ	
Turn-off energy	E _{off}	_	0.82	_	mJ	
Total switching energy	E _{total}	_	1.88	_	mJ	
Short circuit withstand time	t _{sc}	6	8	_	μs	Tc = 100 °C
						$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$
FRD forward voltage	V_{F}	_	1.4	1.9	V	$I_F = 30 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 30 A

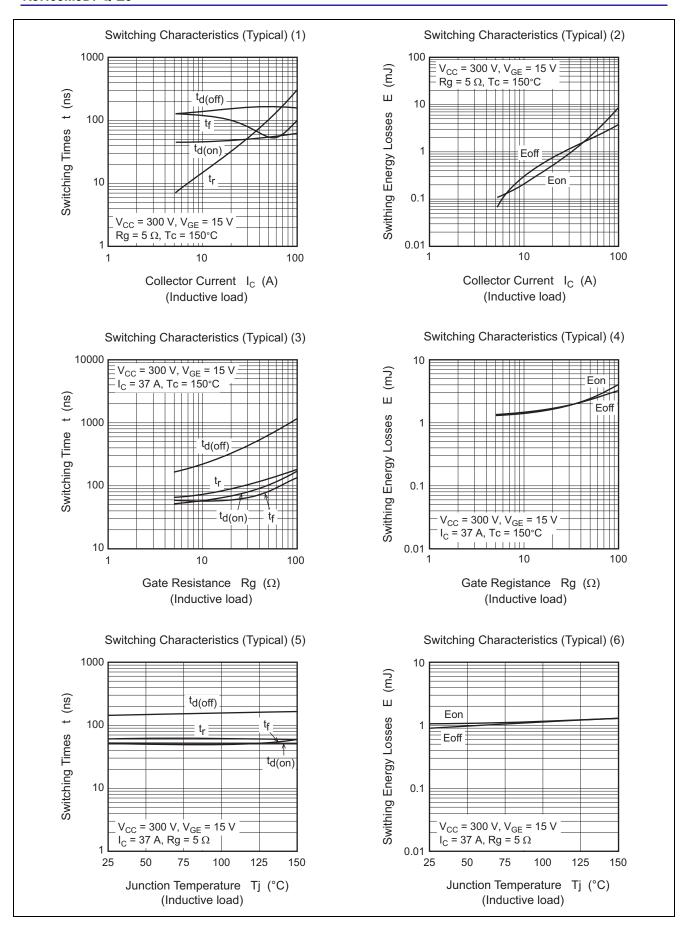
FRD forward voltage	V_{F}	_	1.4	1.9	V	$I_F = 30 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 30 A
FRD reverse recovery charge	Q _{rr}	_	0.19		μC	$di_F/dt = 100 A/\mu s$
FRD peak reverse recovery current	I _{rr}	_	4.9	_	Α	

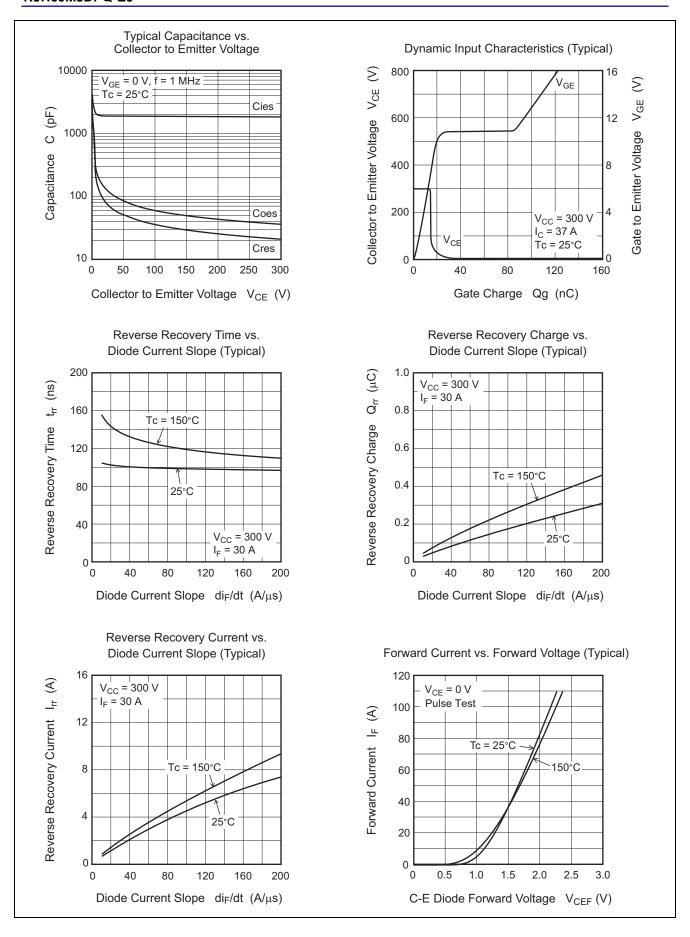
Notes: 3. Pulse test.

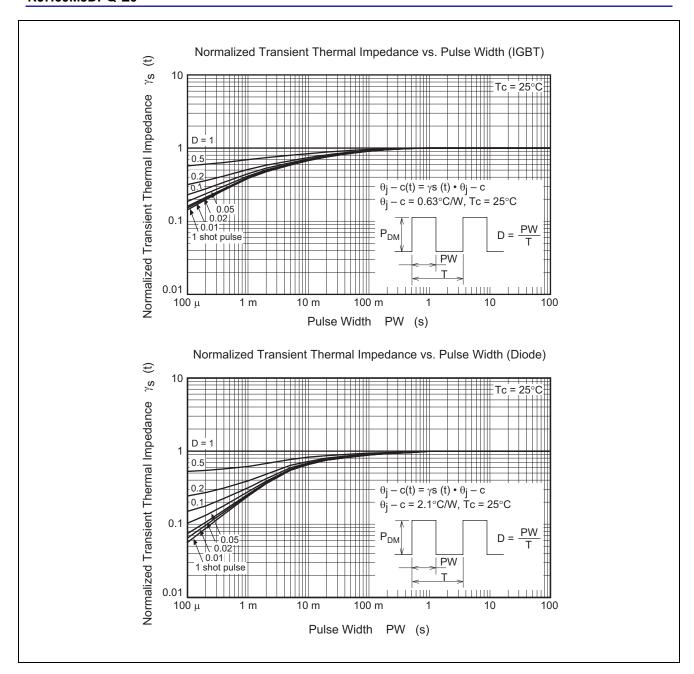
Main Characteristics

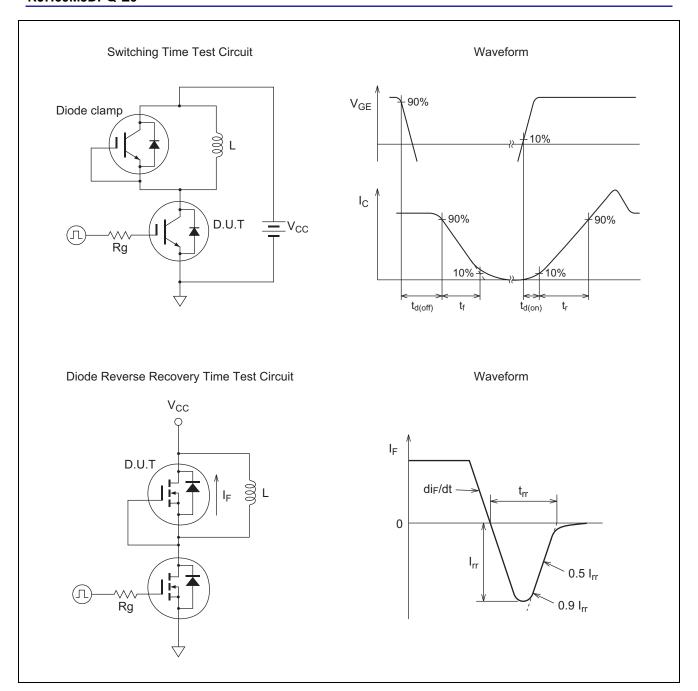




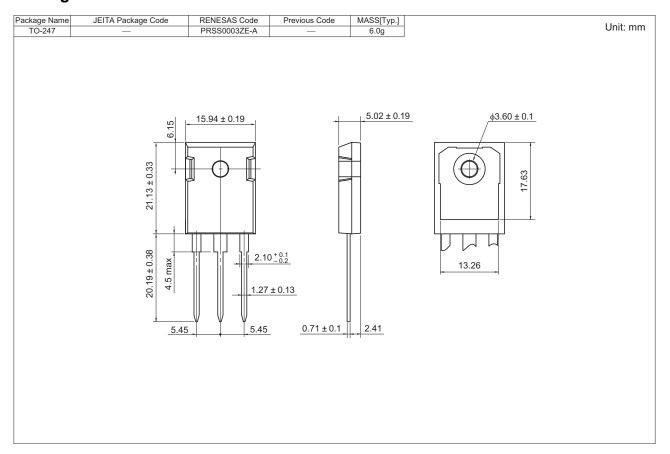








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M5DPQ-E0#T2	450 pcs	Tube

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